BLS9G2735L-50; BLS9G2735LS-50 LDMOS S-band radar power transistor Rev. 1 — 6 October 2017

AMMPLEON

Product data sheet

Product profile

1.1 General description

Single ended 50 W LDMOS power transistor for S-band radar applications in the frequency range from 2.7 GHz to 3.5 GHz.

Typical performance Table 1.

Typical RF performance at T_{case} = 25 °C; t_{p} = 300 μs ; δ = 10 %; I_{Dq} = 100 mA; in a class-AB demo test circuit.

Test signal	f	V _{DS}	P _{L(1dB)}	Gp	η _D
	(GHz)	(V)	(W)	(dB)	(%)
pulsed RF	2.7 to 3.5	32	45	12	48

1.2 Features and benefits

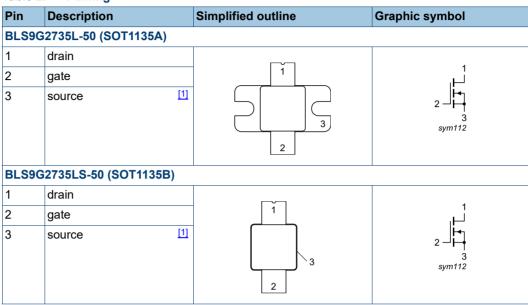
- Single ended
- Small size
- High efficiency
- Excellent ruggedness
- Designed for S-band operation
- Excellent thermal stability
- Easy power control
- Integrated dual sided ESD protection enables excellent off-state isolation
- High flexibility with respect to pulse formats
- Internally matched for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

■ S-band radar applications in the frequency range from 2.7 GHz to 3.5 GHz

2. Pinning information

Table 2. Pinning



^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Packag	Package				
	Name	Description	Version			
BLS9G2735L-50	-	flanged ceramic package; 2 mounting holes; 2 leads	SOT1135A			
BLS9G2735LS-50	-	earless flanged ceramic package; 2 leads	SOT1135B			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Min	Max	Unit
V_{DS}	drain-source voltage	-	65	V
V_{GS}	gate-source voltage	-6	+11	V
T _{stg}	storage temperature	- 65	+150	°C
Tj	junction temperature [1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability. For details refer to the online MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
$Z_{\text{th(j-case)}}$	transient thermal impedance from junction	T_{case} = 85 °C; P_{L} = 50 W		
	to case	t_p = 100 μ s; δ = 10 %	0.315	K/W
		t_p = 200 μ s; δ = 10 %	0.375	K/W
		t_p = 300 μ s; δ = 10 %	0.415	K/W
		t_p = 100 μ s; δ = 20 %	0.375	K/W
		t_p = 500 μ s; δ = 10 %	0.470	K/W
		t_p = 1 ms; δ = 10 %	0.550	K/W

6. Characteristics

Table 6. DC characteristics

 T_i = 25 °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.392 \text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V _{DS} = 10 V; I _D = 39.2 mA	1.5	1.9	2.5	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 32 V	-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	6.4	8.1	-	Α
I _{GSS}	gate leakage current	V _{GS} = 11 V; V _{DS} = 0 V	-	-	140	nA
g _{fs}	forward transconductance	V _{DS} = 10 V; I _D = 39.2 mA	-	360	-	mS
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 1.372 \text{ A}$	-	0.3	-	Ω

Table 7. RF characteristics

Test signal: pulsed RF; 2.9 GHz \leq f \leq 3.4 GHz; t_p = 300 μ s; δ = 10 %; RF performance at V_{DS} = 32 V; I_{Dq} = 100 mA; T_{case} = 25 $^{\circ}$ C; unless otherwise specified, in a class-AB wide band production circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P _L = 50 W	10.3	12	-	dB
η_{D}	drain efficiency	P _L = 50 W	43	48	-	%
RLin	input return loss	P _L = 50 W	-	-8	-	dB
P _{droop(pulse)}	pulse droop power	P _L = 50 W	-	0	0.5	dB
t _r	rise time	P _L = 50 W	-	5	50	ns
t _f	fall time	P _L = 50 W	-	5	50	ns
P _{L(2dB)}	output power at 2 dB gain compression		50	-	-	W

7. Test information

7.1 Ruggedness in class-AB operation

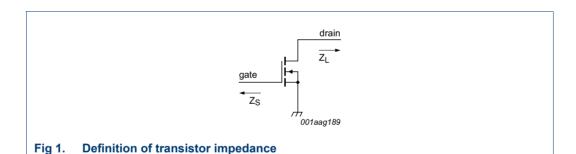
The BLS9G2735L-50 and BLS9G2735LS-50 are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 32 V; I_{Dq} = 100 mA; P_L = 50 W; t_p = 300 μ s; δ = 10 %.

7.2 Impedance information

Table 8. Typical impedance

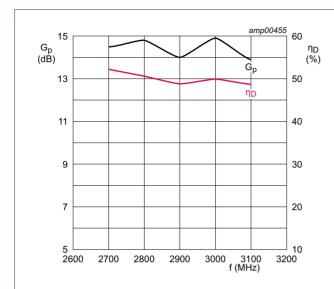
f	Z _S [1]	Z _L [1]
(GHz)	(Ω)	(Ω)
2.9	4.8 – j14.3	5.9 – j8.9
3.0	7.1 – j17.8	6.5 – j9.3
3.1	9.45 – j19.1	8.5 – j7.9
3.2	11.0 – j20.1	7.9 – j6.9
3.3	21.9 – j20.2	7.3 – j6.1
3.4	37.2 – j3.3	4.6 – j4.9

[1] Impedances are taken at a single halve of the push-pull transistor



7.3 Graphical data

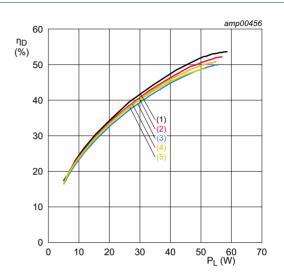
7.3.1 Frequency range from 2.7 GHz to 3.1 GHz



 V_{DS} = 32 V; I_{Dq} = 100 mA; P_L = 50 W; t_p = 300 μs ; δ = 10 %



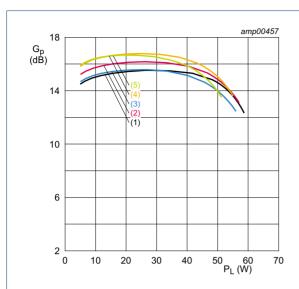
Fig 2. Power gain and drain efficiency as function of frequency; typical values



 V_{DS} = 32 V; I_{Dq} = 100 mA; t_p = 300 $\mu s;$ δ = 10 %.

- (1) f = 2.7 GHz
- (2) f = 2.8 GHz
- (3) f = 2.9 GHz
- (4) f = 3.0 GHz
- (5) f = 3.1 GHz

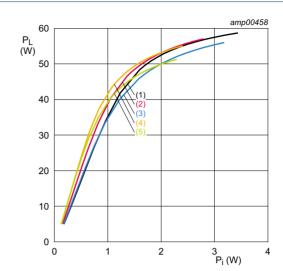
Fig 3. Drain efficiency as a function of output power; typical values



 V_{DS} = 32 V; I_{Dq} = 100 mA; t_p = 300 $\mu s;$ δ = 10 %.

- (1) f = 2.7 GHz
- (2) f = 2.8 GHz
- (3) f = 2.9 GHz
- (4) f = 3.0 GHz
- (5) f = 3.1 GHz

Fig 4. Power gain as a function of output power; typical values

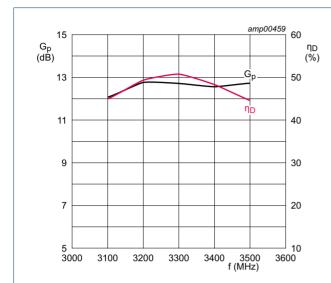


 V_{DS} = 32 V; I_{Dq} = 100 mA; t_p = 300 μ s; δ = 10 %.

- (1) f = 2.7 GHz
- (2) f = 2.8 GHz
- (3) f = 2.9 GHz
- (4) f = 3.0 GHz
- (5) f = 3.1 GHz

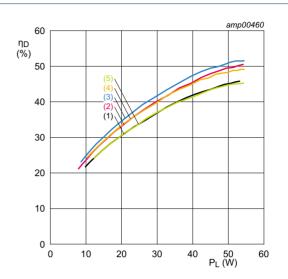
Fig 5. Output power as a function of input power; typical values

7.3.2 Frequency range from 3.1 GHz to 3.5 GHz



 V_{DS} = 32 V; I_{Dq} = 100 mA; P_L = 50 W; t_p = 300 $\mu s;$ δ = 10 %.

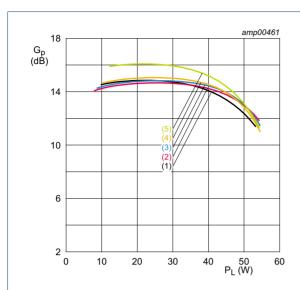




 V_{DS} = 32 V; I_{Dq} = 100 mA; t_p = 300 μ s; δ = 10 %.

- (1) f = 3.1 GHz
- (2) f = 3.2 GHz
- (3) f = 3.3 GHz
- (4) f = 3.4 GHz
- (5) f = 3.5 GHz

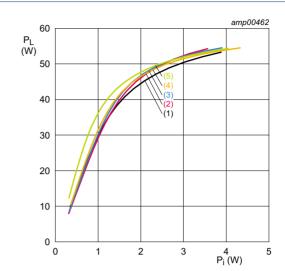
Fig 7. Drain efficiency as a function of output power; typical values



 V_{DS} = 32 V; I_{Dq} = 100 mA; t_p = 300 $\mu s;$ δ = 10 %.

- (1) f = 3.1 GHz
- (2) f = 3.2 GHz
- (3) f = 3.3 GHz
- (4) f = 3.4 GHz
- (5) f = 3.5 GHz

Fig 8. Power gain as a function of output power; typical values



 V_{DS} = 32 V; I_{Dq} = 100 mA; t_p = 300 μ s; δ = 10 %.

- (1) f = 3.1 GHz
- (2) f = 3.2 GHz
- (3) f = 3.3 GHz
- (4) f = 3.4 GHz
- (5) f = 3.5 GHz

Fig 9. Output power as a function of input power; typical values

8. Package outline

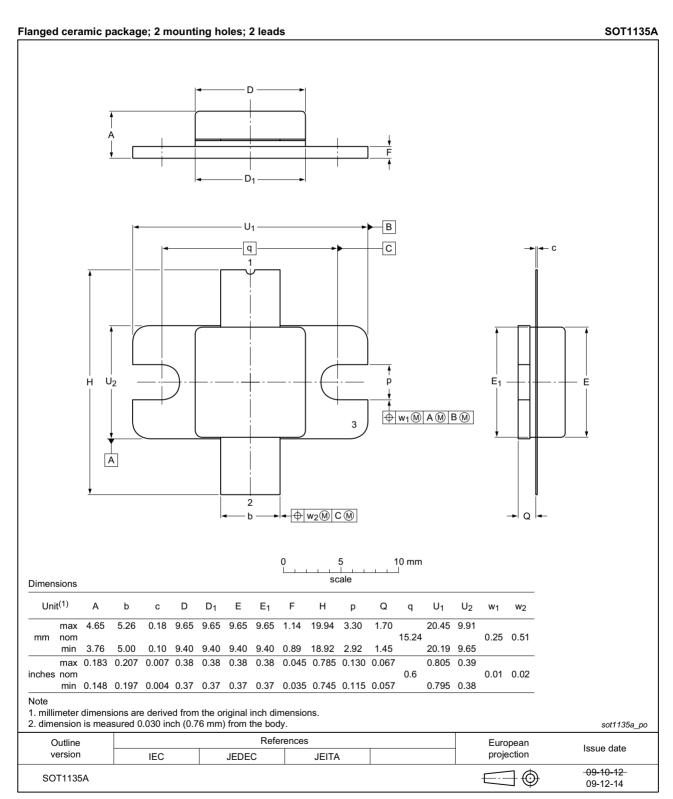


Fig 10. Package outline SOT1135A

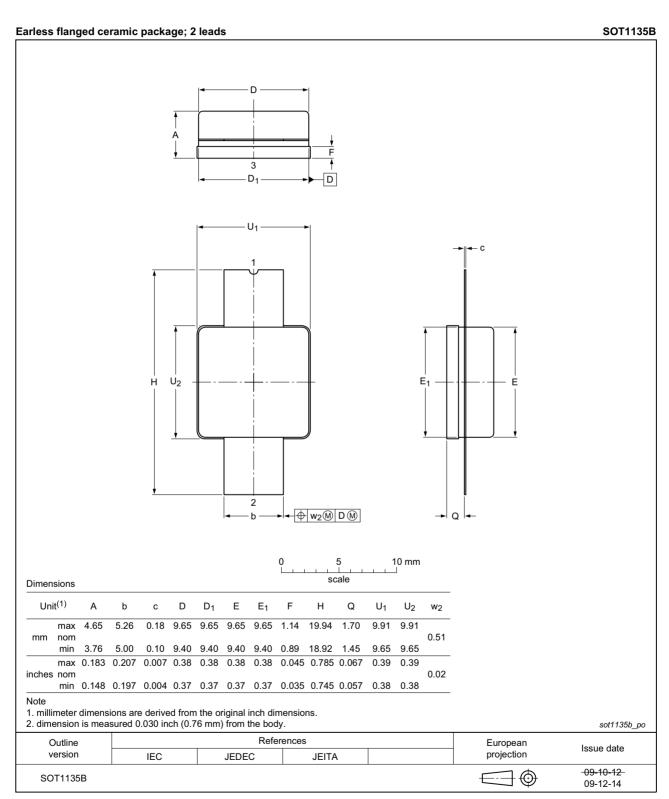


Fig 11. Package outline SOT1135B

Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 9. **ESD** sensitivity

ESD model	Class
Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002	C2A [1]
Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001	2 [2]

- [1] CDM classification C2A is granted to any part that passes after exposure to an ESD pulse of 500 V, but fails after exposure to an ESD pulse of 750 V.
- [2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V, but fails after exposure to an ESD pulse of 4000 V.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
S-band	Short wave Band
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLS9G2735L-50_2735LS-50 v.1	20171006	Product data sheet	-	-

12. Legal information

12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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LDMOS S-band radar power transistor

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LDMOS S-band radar power transistor

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